



EPC2100ENG Information

Part Number EPC2100ENG

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description TRANS GAN 2N-CH 30V BUMPED DIE

Package Die

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EPC2100ENG Specifications

Manufacturer Part Number	EPC2100ENG
Manufacturer	EPC
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	Die
Series	eGaN?
FET Type	2 N-Channel (Half Bridge)
FET Feature	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	9.5A, 38A
Rds On (Max) @ Id, Vgs	8 mOhm @ 25A, 5V
Vgs(th) (Max) @ Id	2.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	3.5nC @ 15V
Input Capacitance (Ciss) (Max) @ Vds	380pF @ 15V
Power - Max	-
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

EPC2100ENG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2100ENG Payment Methods





















EPC2100ENG Shipping Methods













If you have any question about EPC2100ENG, please do not hesitate to contact us!

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